

### High-bandwidth and Low on-resistance Analog switch

#### **Features**

Over-Voltage Tolerance (OVT)

Voltage Operation: 1.8V to 5.5V

• Low On Resistance: 4.5Ω typ at 4.5Vcc

High Off-Isolation

Low Crosstalk

Low leakage current

Low power consumption

Wide -3dB Bandwidth: >300MHz

Low Distortion

Packaged: DQFN10

8kV HBM; 1.5kV CDM ESD Rating

### **Applications**

Cell Phones

PDAs and MP3s

Portable Instrumentation

Battery Powered Communications

Computer Peripherals

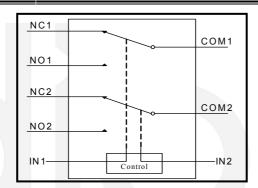
#### **Descriptions**

DIO3712 is a dual, bidirectional, single-pole/double-throw (SPDT) CMOS analog switch, which is designed to operate from a single 1.8V to 5.5V supply. It features high-bandwidth (300MHz) and low on-resistance, targeted applications for full speed USB and audio switching.

DIO3712 features power ON/OFF protection effectively protecting device against external signal perturbation. It also offers excellent -3db bandwidth and lower ON resistance, which can be used as analog switch in multiple applications.

It operates under wide Vcc supply from 1.8V to 5.5V, consuming very low quiescent current even when the voltage of S pin is lower than  $V_{\rm CC}$  supply. This new feature services the mobile handset applications very well allowing for the direct interface with baseband processor general purpose I/Os with no need of level translator.

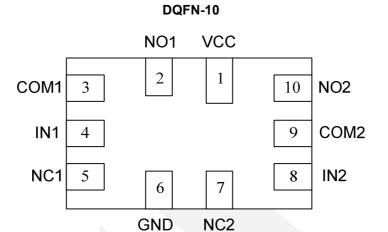
### **Block Diagram**



# **Ordering Information**

Order Part Number	Top Marking	Green	T <sub>A</sub>	Package	
DIO3712LP10	YWGZ	Yes	-40 to +85°C	DQFN-10	Tape & Reel, 3000

# **Pin Assignment**



**Figure 1 Top View** 

# **Pin Descriptions**

Pin Name	Description
Vcc	Power Supply
GND	Ground
COM1, COM2	Common Port
NO1, NO2	Data Port
NC1,NC2	Data Port
IN1, IN2	Control Port

## **Truth Table**

IN	Function
1	COM Connected to NO
0	COM Connected to NC

### **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability

Symbol	Parameter	Min.	Max.	Unit
V <sub>cc</sub>	Supply Voltage	-0.3	+6	V
Vs	DC Switch Voltage	-0.3	V <sub>CC</sub> +0.3	V
V <sub>IN</sub>	DC Input Voltage	-0.3	V <sub>CC</sub> +0.3	V
Isw	Switch Current		±50	mA
Iswpeak	Peak Switch Current (Pulse at 1ms duration, <10% Duty Cycle)		±80	mA
T <sub>STG</sub>	Strorage Temperature Range	-65	150	°C
Тј	Junction Temperature		150	°C
T∟	Lead Temperature Range		260	°C
ESD	HBM, JEDEC: JESD22-A114		8	1.37
	CDM, JEDEC: JESD22-C101		1.5	kV

### **Recommend Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	1.8	5.5	V
V <sub>CNTRL</sub>	Control Input Voltage	1.8	5.5	V
Vsw	Switch Input Voltage	1.8	5.5	V
T <sub>A</sub>	Operating Temperature	-40	85	°C

# **DC Electrical Characteristics**

All typical value are at T<sub>A</sub> = 25°C, unless otherwise specified

Symbol	Parameter	Conditions	Temp.	Min.	Тур.	Max.	Unit	
.,	Input voltage	Vcc=5.0V	40 to 05°C	1.9			V	
V <sub>IH</sub>	high	Vcc=3.0V	40 to 85°C	1.3				
V <sub>IL</sub>	Input voltage	Vcc=5.0V	40 to 85°C			0.9	V	
VIL	low	Vcc=3.0V	-40 to 65 C			0.6	V	
I <sub>IN</sub>	Control input leakage	Vcc=1.8V to 5.5V, V <sub>IN</sub> =0V or 5.5V or 3.6V	-40 to 85°C			1	μΑ	
I <sub>NC(OFF)</sub>	Source off leakage current	Vcc=1.8V to 5.5V, V <sub>NO</sub> or V <sub>NC</sub> =1.0V, 4.5V, V <sub>COM</sub> =4.5V, 1.0V, See Figure 3	-40 to 85°C			2	μΑ	
I <sub>NC(ON)</sub> I <sub>NO(ON)</sub> I <sub>COM(ON)</sub>	On leakage current	Vcc=1.8V to 5.5V, V <sub>NO</sub> or V <sub>NC</sub> =1.0V, 4.5V, V <sub>COM</sub> =1.0V, 4.5V, or floating	-40 to 85°C			2	μΑ	
		Vcc=2.7V, V <sub>NO</sub> or V <sub>NC</sub> =1.2V, I <sub>COM</sub> =-10mA,	25°C		12		Ω	
R <sub>on</sub>	Switch on	See Figure 2	-40 to 85°C			15		
NON	Resistance	Vcc=4.5V, V <sub>NO</sub> or V <sub>NC</sub> =3.5V, I <sub>COM</sub> =-10mA,	25°C		4.5		Ω	
		See Figure 2	-40 to 85°C			5.0	12	
		Vcc=2.7V,	25°C			0.3	Ω	
ΔR <sub>on</sub>	On Resistance V <sub>NO</sub> or V <sub>NC</sub> =1.5V, I <sub>COM</sub> =-10mA Matching	V <sub>NO</sub> or V <sub>NC</sub> =1.5V, I <sub>COM</sub> =-10mA	-40 to 85°C			0.8		
	between Channels		25°C			0.2	Ω	
		$V_{NO}$ or $V_{NC}$ =3.5V, $I_{COM}$ =-10mA	-40 to 85°C			0.8		
RELT/ON)	On Resistance	Vcc=2.7V, V <sub>NO</sub> or V <sub>NC</sub> =1.0V, 1.5V, 2.0V, I <sub>COM</sub> =-10mA	-40 to 85°C		5.0		Ω	
	Flatness	Vcc=4.5V, V <sub>NO</sub> or V <sub>NC</sub> =1.0V, 2.0V, 3.5V, I <sub>COM</sub> =-10mA	-40 to 85°C		1.6		22	
I <sub>cc</sub>	Power Supply Current	Vcc=1.8V to 5.5V, V <sub>IN</sub> =0V or Vcc	-40 to 85°C			5	μΑ	

### **AC Electrical Characteristics**

All typical value are at Vcc=1.8 to 5.5V, T<sub>A</sub>=25°C unless otherwise specified

Symbol	Parameter	Conditio	Temp.	Min.	Тур.	Max.	Unit	
T <sub>ON</sub>	Turn-On Time	$V_{NO}$ or $V_{NC}$ =1.5V,R <sub>L</sub> = C <sub>L</sub> = 35pF,See Figure	25°C			23	ns	
T <sub>OFF</sub>	Turn-Off Time	$V_{NO}$ or $V_{NC}$ =1.5V,RL = 300 $\Omega$ , C <sub>L</sub> = 35pF,See Figure 9		25°C			20	ns
Tbbm	Break-Before -Make Time	$V_{NO1}$ or $V_{NC1}$ = $V_{NO2}$ or $V_{NC2}$ = 1.5V, R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35Pf,See Figure 8		25°C			6	ns
OIRR	Off Isolation	$R_L = 50\Omega$ , Signal=0dBm	f=10MHz	25°C		-57		dB
OIKK	Oli isolation	C <sub>L</sub> = 5pF See Figure 7	f=1MHz	25°C		-75		uв
Xtalk	Crosstalk	$R_L = 50\Omega$ , Signal=0dBm,	f=10MHz	25°C		-96		dB
Alaik	Ciossiaik	C <sub>L</sub> = 5pF See Figure 6	f=1MHz	25°C		-100		uв
BW	-3dB bandwidth	$R_L = 50\Omega$ , Signal=0dE $C_L = 5pF$ , See Figure		25°C		300		MHz

### **AC Electrical Characteristics(continued)**

All typical value are for Vcc = 3.3V at 25°C unless otherwise specified

Symbol	Parameter		Conditions	Temp.	Min.	Тур.	Max.	Unit
C <sub>ON</sub>	On Capacitance, See Figure 4	f=1MHz		25°C		10		pF

## **Test Diagrams**

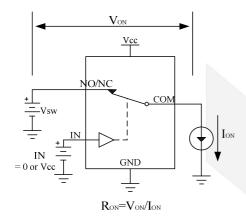


Figure 2 Switch on resistor

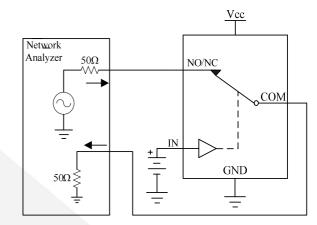


Figure 5 Bandwidth

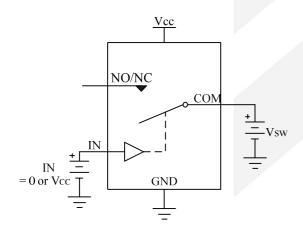


Figure 3 Switch Off Leakage

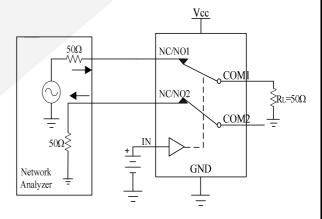


Figure 6 Channel-to-channel crosstalk

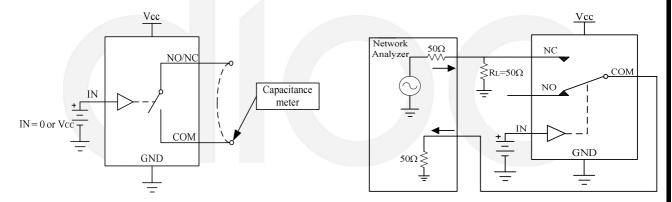


Figure 4 On/off Capacitance test

Figure 7 Off-isolation

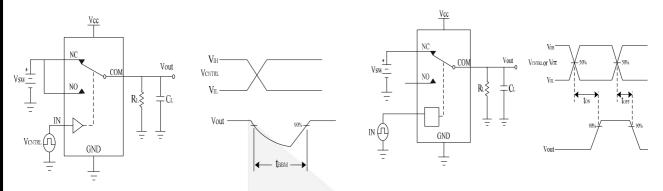


Figure 8 Break-Before-Make

Figure 9 Turn-On/Turn-Off

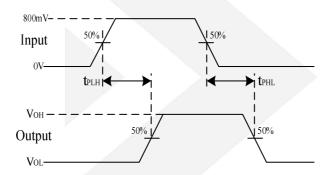
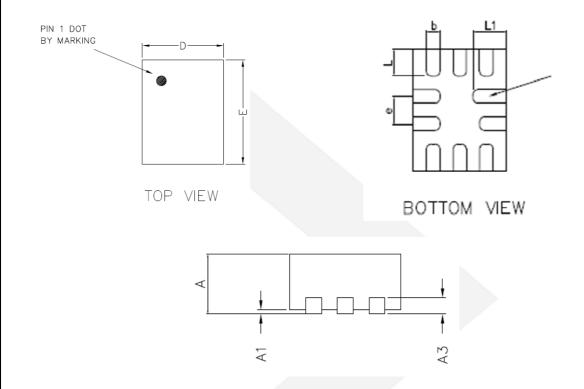


Figure 10 Propagation delay

# **Physical Dimensions: DQFN10**



COMMON DIMENSIONS(MM)							
PKG.	UT:ULTRA THIN						
REF.	MIN. NOM MAX						
Α	0.5	0.55	0.6				
A1	0 0.05						
A3	0.15REF.						
D	1.35	1.4	1.45				
E	1.75	1.8	1.85				
b	0.15	0.2	0.25				
L	0.3	0.4	0.5				
L1	0.4	0.5	0.6				
е	0.4BSC						

### **CONTACT US**

**D**ioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipments and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to <a href="http://www.dioo.com">http://www.dioo.com</a> for a complete list of Dioo product families.

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